# **LITEON** LITE-ON TECHNOLOGY CORPORATION

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#### **FEATURES**

**\***RECTANGULAR LIGHT BAR \*LARGE, BRIGHT, UNIFORM LIGHT EMITTING AREAS **\*LOW POWER REQUIREMENT \* HIGH BRIGHTNESS & HIGH CONTRAST \* SOLID STATE RELIABILITY \***CATEGORIZED FOR LUMINOUS INTENSITY

#### DESCRIPTION

The LTA-1000G-NB is a ten rectangular light sources array display designed for a variety of applications where a continuously large, bright source of light is required. This device uses Green LED chips (GaP epi on GaP substrate). The display has black face and white segments.

### DEVICE

PART NO.	DESCRIPTION
Green	Universal
LTA-1000G-NB	Ten Rectangular Bar

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#### **PIN CONNECTION**

No.	CONNECTION					
1	ANODE A					
2	ANODE B					
3	ANODE C					
4	ANODE D					
5	ANODE E					
6	ANODE F					
7	ANODE G					
8	ANODE H					
9	ANODE J					
10	ANODE K					
11	CATHODE K					
12	CATHODE J					
13	CATHODE H					
14	CATHODE G					
15	CATHODE F					
16	CATHODE E					
17	CATHODE D					
18	CATHODE C					
19	CATHODE B					
20	CATHODE A					

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#### **ABSOLUTE MAXIMUM RATING**

PARAMETER	MAXIMUM RATING	UNIT		
Power Dissipation Per Segment	75	mW		
Peak Forward Current Per Segment	100*			
(Frequency 1Khz, 10% duty cycle )	100*	mA		
Continuous Forward Current Per Segment	25	mA		
Forward Current Derating from 25 <sup>o</sup> C	0.33	mA/°C		
Reverse Voltage Per Segment	5	V		
Operating Temperature Range $-35^{\circ}$ C to $+85^{\circ}$ C				
Storage Temperature Range	-35°C to +85°C			
Soldering Conditions : $1/16$ inch below seating plane for 3 seconds at $260^{\circ}$ C				

\* see figure 5 to establish pulsed condition

#### ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	540	2000		μcd	IF=10mA
Peak Emission Wavelength	λp		565		nm	IF=20mA
Spectral Line Half-Width	Δλ		30		nm	IF=20mA
Dominant Wavelength	λd		569		nm	IF=20mA
Forward Voltage Per Segment	VF		2.1	2.6	V	IF=20mA
Reverse Current Per Segment	Ir			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	Iv-m			2:1		IF=10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

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